Title

Submillimeter and Microwave Residual Losses in Epitaxial Films of Y-Ba-Cu-O and Tl-Ca-Ba-Cu-O

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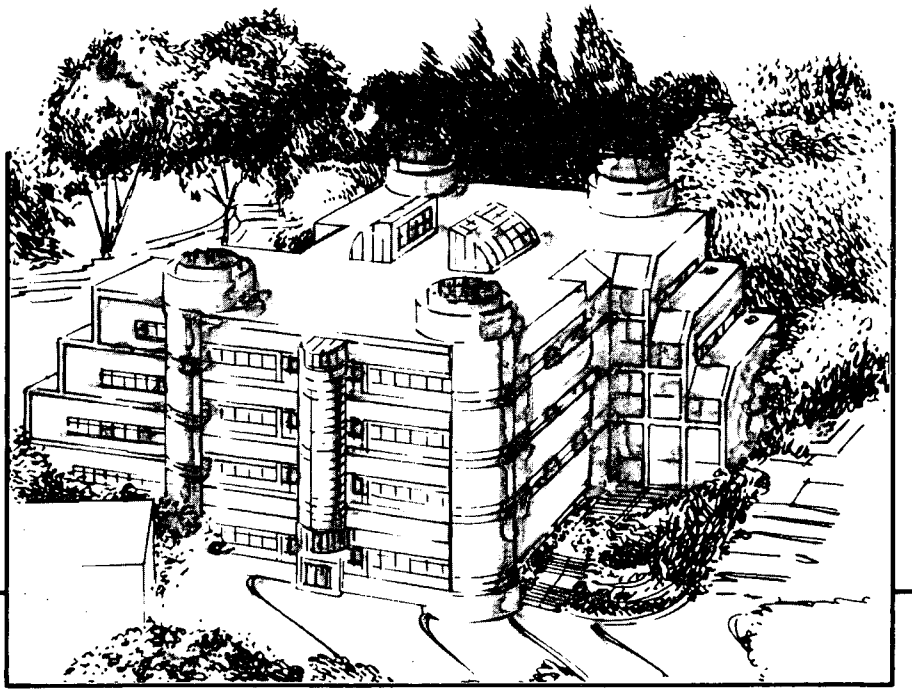

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DISCLAIMER

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ABSTRACT

We have used a novel bolometric technique and a resonant technique to obtain accurate submillimeter and microwave residual loss data for epitaxial thin films of $YBa_2Cu_3O_7$, $Tl_2Ca_2Ba_2Cu_3O_{10}$ and $Tl_2CaBa_2Cu_2O_8$. For all films we obtain good agreement between the submillimeter and microwave data, with the residual losses in both the Y-Ba-Cu-O and Tl-Ca-Ba-Cu-O films scaling aproximately as frequency squared below ~ 1 THz. We are able to fit the losses in the Y-Ba-Cu-O films to a two fluid and a weakly coupled grain model for the a-b plane conductivity, in good agreement with results from a Kramers-Kronig analysis of the loss data.

EXPERIMENTAL APPROACH

We have developed a novel technique for directly measuring the residual loss of high-T_c thin films.[1] In this technique the high-T_c film is used as the absorber in a composite bolometric detector for the signal from a Fourier transform spectrometer with a Hg arc source. Our technique allows us to obtain accurate direct absorptivity data on epitaxial a-b plane films in the frequency range between microwave loss and infrared reflectivity measurements. The residual losses in the $YBa_2Cu_3O_7$ films used for this study were also measured near 10 GHz using microwave cavity techniques,[2] and are among the lowest reported in the literature. The residual losses in the Tl-Ca-Ba-Cu-O films used in this study were measured near 10 GHz using microwave cavity techniques[2] and near 30 and 90 GHz using a confocal resonator technique.[3] Using the well documented frequency squared dependence of the microwave loss up to 100 GHz,[4] we can infer the loss in our films over four decades in frequency.

RESULTS

The a-b plane oriented $YBa_2Cu_3O_7$ samples used in this study were grown on MgO and $LaAlO_3$ substrates using off-axis sputtering[5, 6] and laser ablation techniques.[7, 8] These samples are notable for their lack of impurity phase and high degree of epitaxial alignment. The a-b plane oriented $Tl_2CaBa_2Cu_2O_8$ sample S1 was grown on a $LaAlO_3$ substrate by laser deposition followed by a post deposition anneal,[9] and the mixed phase $Tl_2Ca_2Ba_2Cu_3O_{10}$ and $Tl_2CaBa_2Cu_2O_8$ films L1 and L2 were grown on $LaAlO_3$ substrates using an off-axis sputtering technique followed by a post-annealed with the amorphous 2:2:2:3 precursor films surrounded by 2:2:2:3 pellets in order to minimize Tl_2O_3 loss.[10] The results of our measurements are shown in Figs. 1 and 2.

CONCLUSIONS

We have characterized the residual loss in epitaxial a-b plane films of $YBa_2Cu_3O_7$, $Tl_2CaBa_2Cu_2O_8$ and mixed phase $Tl_2Ca_2Ba_2Cu_3O_{10}$ and $Tl_2CaBa_2Cu_2O_8$ films from 10 GHz to 21 THz. We do not observe any gap-like features below 15 THz for any of the films studied. For all films studied the losses below ~ 1 THz scale approximately as frequency squared.

We have shown that the frequency dependence of the loss below 13.5 THz for the $YBa_2Cu_3O_7$ films can be well represented by a two fluid or a weakly coupled grain model.[1, 11] We find remarkable agreement between the results of a Kramers-Kronig analysis and the best fits from the weakly coupled grain model below 15 THz for

all films.[12] These results suggest that weak link behavior may play a significant role in the microwave and submillimeter losses.

We are unable to fit the losses in the Tl-Ca-Ba-Cu-O films either to the two fluid or to the weakly coupled grain models. We observe strong phonon structure in the Tl-Ca-Ba-Cu-O films between 1 and 21 THz. This is in strong contrast to the case for other high-T_c superconductors such as $YBa_2Cu_3O_7$, where phonon structure observed in ceramic samples is absent in epitaxial oriented films and crystals because of the electronic screening due to the high conductivity of the a-b planes.

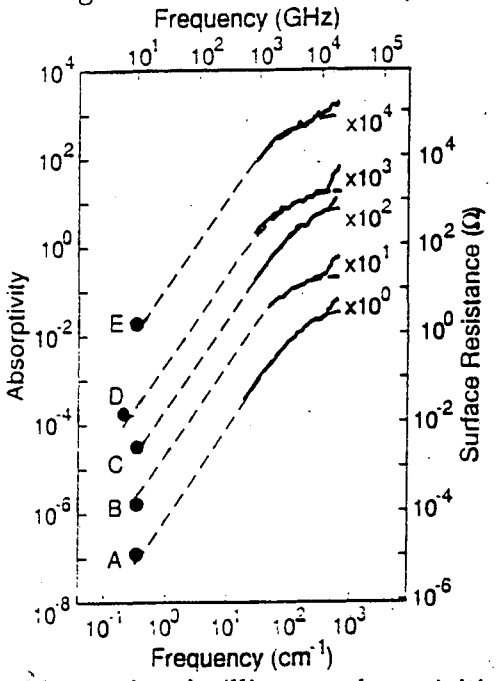

Fig. 1. Measured submillimeter absorptivities of samples A through E at 2K (solid lines) multiplied by the indicated factors to separate the curves. Values of the microwave surface resistance are shown as filled circles are measured for each sample at 4K at the frequency indicated. Also shown are best fits to the weakly coupled grain model.

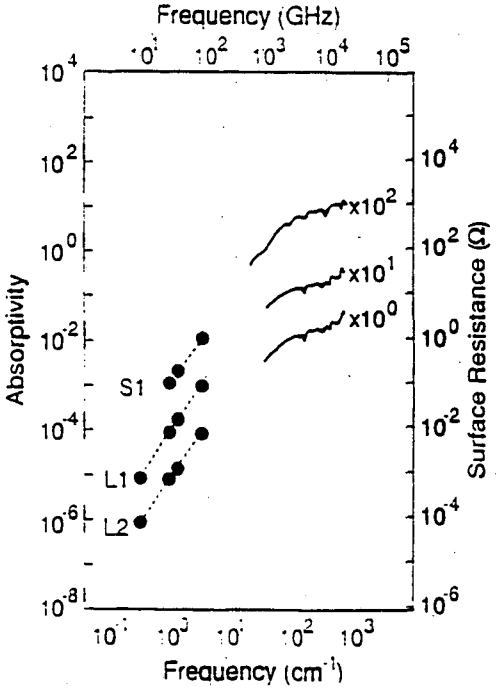

FIG. 2. Measured submillimeter absorptivities of samples L1, L2 and S1 at 2K (solid lines) multiplied by the indicated factors to separate the curves. Values of the microwave surface resistance measured for each sample near 4K are shown as filled circles. The dotted lines are best fits to the microwave surface resistance data using an ω^2 dependence, where ω is the microwave frequency.

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